

SHENZHEN HAOLIN ELECTRONICS TECHNOLOGY CO., LTD

# **TO-126 Plastic-Encapsulate Transistors**

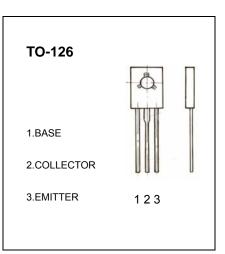
### HR13003

TRANSISTOR (NPN)

FEATURES High total power disspation. (p<sub>c</sub>=1.25w) MARKING:MJE13003

#### MAXIMUM RATINGS (T<sub>A</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	600	V
V <sub>CEO</sub>	Collector-Emitter Voltage	480	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
lc	Collector Current -Continuous	1	А
Pc	Collector Dissipation	1.25	W
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature	-55-150	°C



#### ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

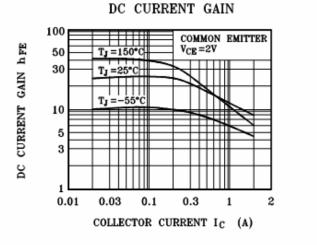
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μΑ, I <sub>E</sub> =0	600			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 1mA,I <sub>B</sub> =0	480			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100μΑ,I <sub>C</sub> =0	6			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 600V,I <sub>E</sub> =0			100	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 6 V,I <sub>C</sub> =0			100	μA
DC ourrent gain	h <sub>FE1</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 250 µA	5			
DC current gain	h <sub>FE2</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 200mA	9		40	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =200mA, I <sub>B</sub> = 40mA			0.8	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =200mA, I <sub>B</sub> = 40mA			1.2	V
Transition frequency	f⊤	V <sub>CE</sub> =10V, I <sub>C</sub> =100mA f =1MHz	5			MHz
Fall time	t <sub>f</sub>	I <sub>C</sub> =1A, I <sub>B1</sub> =-I <sub>B2</sub> =0.2A			0.8	μs
Storage time	ts	V <sub>CC</sub> =100V			3.5	μs

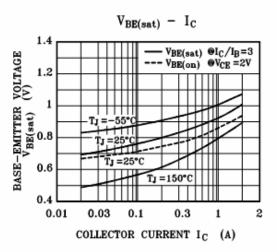
#### CLASSIFICATION OF h<sub>FE2</sub>

Rank						
Range	9-15	15-20	20-25	25-30	30-35	35-40

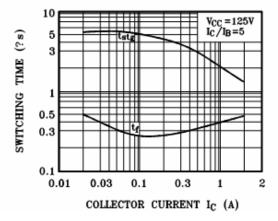
### **Typical Characteristics**

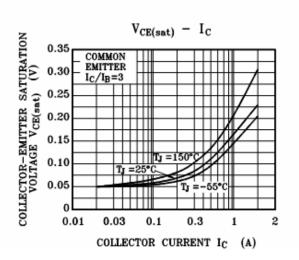
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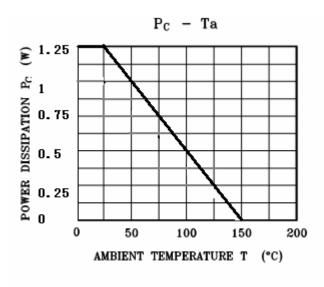




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 2SC2712S-GR,LF
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